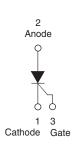


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Thyristor Surface Mount, Phase Control SCR, 8 A

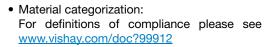




PRODUCT SUMMARY						
TO-263AB (D ² PAK)						
Single SCR						
8 A						
800 V						
1.2 V						
15 mA						
- 40 to 125 °C						

FEATURES

- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Designed and qualified according JEDEC-JESD47







ROHS COMPLIANT HALOGEN FREE

APPLICATIONS

- Input rectification and crow-bar (soft start)
- Vishay input diodes, switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-12TTS08SPbF High Voltage Series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125 °C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS							
APPLICATIONS SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS							
Capacitive input filter $T_A = 55$ °C, $T_J = 125$ °C, common heatsink of 1 °C/W	13.5	17	А				

MAJOR RATINGS AND CHARACTERISTICS							
PARAMETER	TEST CONDITIONS	VALUES	UNITS				
I _{T(AV)}	Sinusoidal waveform	8	۸				
I _{T(RMS)}		12.5	Α				
V _{RRM} /V _{DRM}		800	V				
I _{TSM}		110	Α				
V _T	8 A, T _J = 25 °C	1.2	V				
dV/dt		150	V/µs				
dl/dt		100	A/µs				
TJ	Range	- 40 to 125	°C				

VOLTAGE RATINGS									
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{DRM} , MAXIMUM PEAK DIRECT VOLTAGE V	I _{RRM} /I _{DRM} AT 125 °C mA						
VS-12TTS08SPbF	800	800	1.0						



ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL		TEST CONDITIONS	VALUES	UNITS		
Maximum average on-state current	I _{T(AV)}	T 100 °C	190° conduction half ains ways	8			
Maximum RMS on-state current	I _{T(RMS)}	1 _C = 106 C,	180° conduction, half sine wave	12.5	۸		
Maximum peak one-cycle	1	10 ms sine pu	ulse, rated V _{RRM} applied, T _J = 125 °C	95	Α		
non-repetitive surge current	I _{TSM}	10 ms sine pu	ulse, no voltage reapplied, T _J = 125 °C	110			
Maximum I ² t for fusing	l ² t	10 ms sine pu	ulse, rated V _{RRM} applied, T _J = 125 °C	45	A ² s		
Maximum i-t for fusing	1-1	10 ms sine pu	ulse, no voltage reapplied, T _J = 125 °C	64	A-5		
Maximum I ² √t for fusing	I ² √t	t = 0.1 ms to	10 ms, no voltage reapplied, $T_J = 125 ^{\circ}\text{C}$	640	A²√s		
Maximum on-state voltage drop	V _{TM}	8 A, T _J = 25 °C		1.2	V		
On-state slope resistance	r _t	T 405.00		16.2	mΩ		
Threshold voltage	V _{T(TO)}	T _J = 125 °C		0.87	V		
Maximum reverse and direct lookage augrent	1 //	T _J = 25 °C	$V_R = Rated V_{RRM}/V_{DRM}$	0.05			
Maximum reverse and direct leakage current	I _{RM} /I _{DM}	T _J = 125 °C	v _R = nated v _{RRM} /v _{DRM}	1.0			
Typical holding current	I _H	Anode supply = 6 V, resistive load, initial I_T = 1 A, T_J = 25 °C		30	mA		
Maximum latching current	IL	Anode supply = 6 V, resistive load, T _J = 25 °C		50			
Maximum rate of rise of off-state voltage	dV/dt	$T_J = T_J \text{ max.},$	linear to 80 %, V _{DRM} = R _g - k = Open	150	V/µs		
Maximum rate of rise of turned-on current	dI/dt			100	A/µs		

TRIGGERING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum peak gate power	P _{GM}		8.0	W			
Maximum average gate power	P _{G(AV)}		2.0	VV			
Maximum peak positive gate current	+ I _{GM}		1.5	Α			
Maximum peak negative gate voltage	- V _{GM}		10	V			
		Anode supply = 6 V, resistive load, T _J = - 65 °C	20				
Maximum required DC gate current to trigger	I_{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	15	mA			
		Anode supply = 6 V, resistive load, T _J = 125 °C	10				
		Anode supply = 6 V, resistive load, T _J = - 65 °C	1.2				
Maximum required DC gate voltage to trigger	V_{GT}	Anode supply = 6 V, resistive load, T _J = 25 °C	1	V			
		Anode supply = 6 V, resistive load, T _J = 125 °C	0.7	V			
Maximum DC gate voltage not to trigger	V_{GD}	T. = 125 °C V Potod value	0.2				
Maximum DC gate current not to trigger	I _{GD}	T _J = 125 °C, V _{DRM} = Rated value	0.1	mA			

SWITCHING							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Typical turn-on time	t _{gt}	T _J = 25 °C	0.8				
Typical reverse recovery time	t _{rr}	T 105 °C	3	μs			
Typical turn-off time	t _q	T _J = 125 °C	100				



THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum junction and st temperature range	orage	T _J , T _{Stg}		- 40 to 125	°C		
Maximum thermal resista junction to case	nce,	R_{thJC}	DC operation	1.5			
Maximum thermal resista junction to ambient	nce,	R _{thJA}		62	°C/W		
Typical thermal resistance case to heatsink	9,	R _{thCS}	Mounting surface, smooth and greased	0.5			
Annavimate weight				2	g		
Approximate weight				0.07	OZ.		
Mounting torque	minimum			6 (5)	kgf · cm		
Mounting torque -	maximum			12 (10)	(lbf \cdot in)		
Marking device			Case style D ² PAK (SMD-220)	12TT:	S08S		

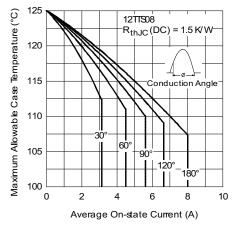


Fig. 1 - Current Rating Characteristics

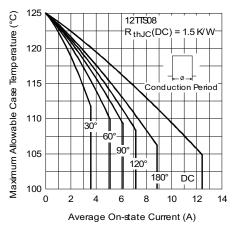


Fig. 2 - Current Rating Characteristics

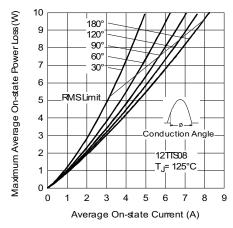


Fig. 3 - On-State Power Loss Characteristics

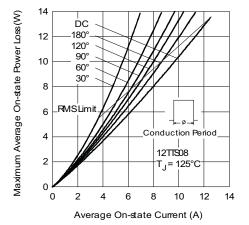


Fig. 4 - On-State Power Loss Characteristics

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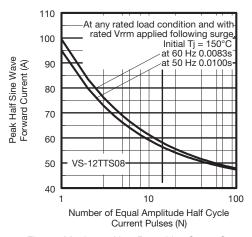


Fig. 5 - Maximum Non-Repetitive Surge Current

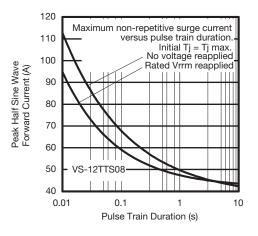


Fig. 6 - Maximum Non-Repetitive Surge Current

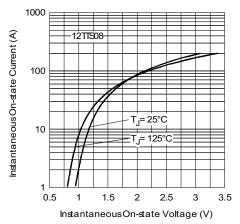


Fig. 7 - On-State Voltage Drop Characteristics

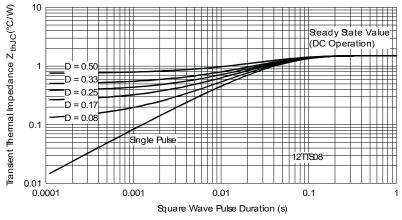
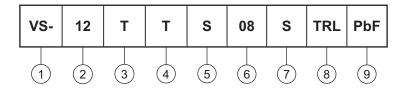


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

Current rating (12.5 A)

Circuit configuration:

T = Single thyristor

4 - Package:

T = TO-220AC

5 - Type of silicon:

S = Standard recovery rectifier

6 - Voltage rating (08 = 800 V)

7 - S = TO-220 D²PAK (SMD-220) version

8 - • None = Tube

• TRL = Tape and reel (left oriented)

• TRR = Tape and reel (right oriented)

9 - PbF = Lead (Pb)-free

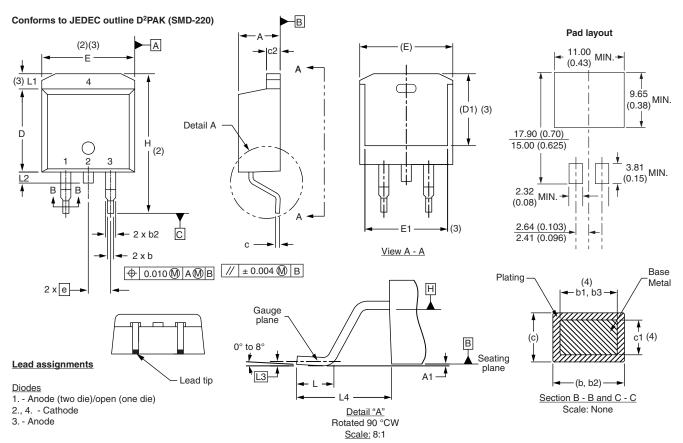
ORDERING INFORMATION (Example)								
PREFERRED P/N QUANTITY PER T/R MINIMUM ORDER QUANTITY PACKAGING DESCRIPTION								
VS-12TTS08SPbF	50	1000	Antistatic plastic tubes					
VS-12TTS08STRRPbF	800	800	13" diameter reel					
VS-12TTS08STRLPbF	800	800	13" diameter reel					

LINKS TO RELATED DOCUMENTS						
Dimensions	www.vishay.com/doc?95046					
Part marking information	www.vishay.com/doc?95054					
Packaging information	www.vishay.com/doc?95032					



D²PAK

DIMENSIONS in millimeters and inches



SYMBOL	MILLIN	IETERS	INC	NOTES	
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INC	NOTES	
STWBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100	BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	1	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

- $^{(1)}$ Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch
- (7) Outline conforms to JEDEC outline TO-263AB



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